## H<sup>-</sup> ion source caesiations at other labs

180<sup>th</sup> Machine Protection Panel Meeting, Continuous caesiation at Linac 4 CERN, 30.08.2019

#### H<sup>-</sup> ion source types

#### Caesiation hardware and methods

- o BNL
- o FNAL
- o J-PARC
- o RAL
- o ORNL

#### Summary

Acknowledgements

Deepak Raparia (BNL), Daniel Bollinger (FNAL), Dan Faircloth (RAL) Akira Ueno (J-PARC), Martin Stockli (ORNL)

## Ion sources for particle accelerators

#### 17<sup>th</sup> International Conference on Ion Sources

October 15-20. 2017 CERN, CICG, Geneva

#### International Advisory Committee

Yong-Seok Hwang, Seoul Nat'l Univ Alexander Ivanov, BINP Ka-Ngo Leung, UCE Marc Loiselet, UCL Fakahide Nakagawa, RIKEN Richard Pardo, ANL



P. Loïez 2002



Ion sources, 29 May - 8 June 2012, Senec, Slovakia



**RELATED LINKS** 

Indico page

Hotel Senec<sup>®</sup>

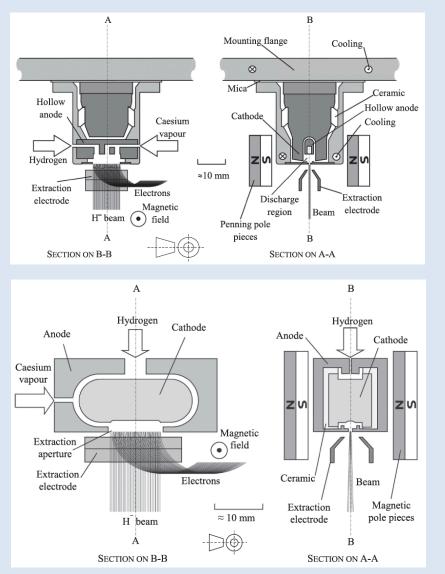
DOWNLOADABLE



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## H<sup>-</sup> ion sources types (1)



#### Penning surface plasma ion source

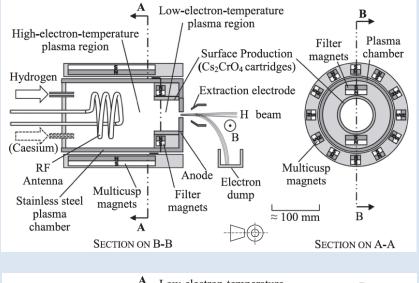
ISIS, STFC Rutherford Appleton Laboratory (RAL), UK

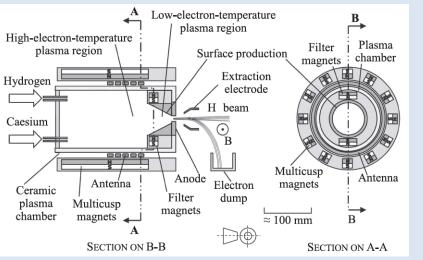
#### Magnetron surface plasma ion source

Brookhaven National Laboratory (BNL), USA Fermi National Accelerator Laboratory (FNAL), USA

D. Faircloth, S. Lawrie, New J. Phys. 20 (2018) 025007

## H<sup>-</sup> ion sources types (2)





# Internal RF solenoid antenna driven volume & surface plasma ion source

Japan Proton Accelerator Research Complex (J-PARC), Japan SNS, Oak Ridge National Laboratory (ORNL), USA

External RF solenoid antenna driven volume & surface plasma ion source LINAC4, CERN, Switzerland

D. Faircloth, S. Lawrie, New J. Phys. 20 (2018) 025007

# Comparison of sources currently operating on accelerator facilities or accelerator test stands

Source	Variant	Technology	Caesium	Beam current
D-Pace D-Pace	Filament RF	Filament-driven volume External planar antenna RF- driven volume	No No	18 mA 8 mA
ISIS ISIS BINP	Operations FETS CW	Penning surface plasma Penning surface plasma Penning surface plasma	Yes, elemental Yes, elemental Yes, caesium chromate	55 mA 80 mA 25 mA
FNAL BNL LANL	Operations Operations LANSCE	Magnetron surface plasma Magnetron surface plasma Filament-driven surface convertor	Yes, elemental Yes, elemental Yes, elemental	80 mA 100 mA 18 mA
SNS	Operations	Internal solenoid antenna RF-driven volume and surface	Yes, caesium chromate	>60 mA
J-PARC	Operations	Internal solenoid antenna RF-driven volume and surface	Yes, elemental	45 mA (test stand 66 mA)
CERN	Linac4	External solenoid antenna RF-driven volume and surface	Yes, elemental	45 mA

D. Faircloth, S. Lawrie, New J. Phys. 20 (2018) 025007

## Other labs

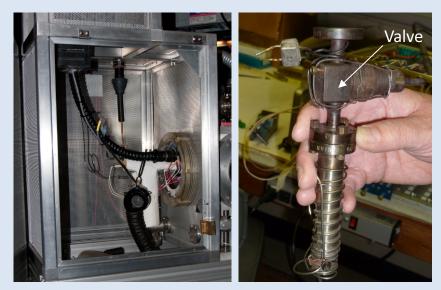
- Five accelerator laboratories contacted (24 July 2019) for up-to-date ion source and caesiation system information, contacted experts:
- Deepak Raparia (BNL), Daniel Bollinger (FNAL), Akira Ueno (J-PARC),
- Dan Faircloth + Oli Tarvainen (RAL), Robert Welton + Martin Stockli (ORNL)
- The Linac4 team would highly appreciate if you could prepare and send me a few slides summarizing your ion source caesition system, which is presently in accelerator use. The following specific points are very welcome:
- a brief description of your Cs hardware system, preferably with some photos,
- temperatures, durations, and repetition(s) applied during caesiation,
- approximate *Cs consumption* per month or per year,
- the total amount of Cs in your oven/system,
- measures and/or equipment to protect the linac especially the RFQ against Cs,
- observed/solved **problems in the past**, either associated with your Cs system or in the beamline.

Remark: On the following slides all expert replies are quoted with blue text

## BNL

#### Magnetron, continuous caesiation

D. Raparia



#### Cs hardware system for BNL source

- Cs oven heated up to 100-120 °C
- Valve and feed line up to 300 °C
- It is covered by insulator

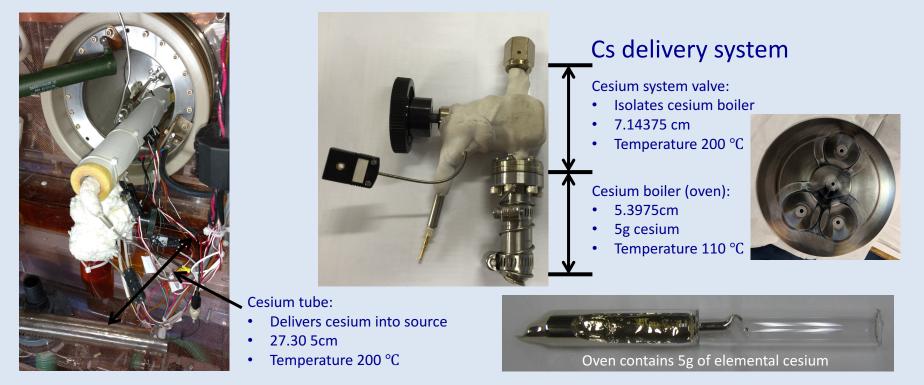
Temperatures, durations, and repetition(s) applied during caesiation?

- At start up **125-130** °C for about **8 hours**, then reduce to **90-110** °C for rest of the operation (> 6 months)
- Approximate Cs consumption per month or per year? ~ 0.5 mg/hour
- Total amount of Cs in your oven/system? 5 g
- Measures and/or equipment to protect the linac especially the RFQ against Cs?
- None; LEBT with 45 degree bend is about 2 meter, never had any issues with Cs in RFQ
- Observed / solved problems in the past, either associated with your Cs system or in the beamline.
- Cs valve failure once in last 25 year, clogging at opening of feed line in the source once in 25 years

## **FNAL**

#### Magnetron, continuous caesiation

D. Bollinger

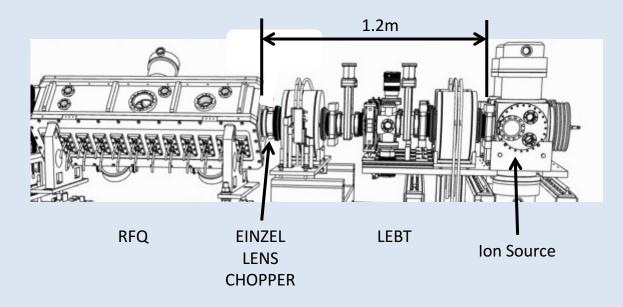


- Typical cesium system temperatures: oven 110 °C, valve 200 °C, tube 200 °C
- Cesium consumption is 5g/600days, note: the cesium oven is typically not completely empty after 600 days
- No machine protection to address cesium in beamline and RFQ
- No issues with cesium in RFQ or HV element in LEBT since RFQ upgrade in 2012
- No method of trapping cesium coming out of the source
- Current FNAL ion source annual operations: 9 months continuous running, 3 months summer shutdown

## **FNAL**

### Magnetron, continuous caesiation

D. Bollinger





Ion source facing side of the extractor after 9 months operation does have cesium deposits

- The **RFQ** is about **1.2m from** the **ion source**
- There is an Einzel Lens at the entrance to the RFQ. It operates at 38kV. There have been no issues with cesium deposits on the lens
- The only time that we see the entrance to the RFQ is when the Einzel Lens is removed due to failure. We have not had an Einzel Lens failure in 2 years (the lens was redesigned due to previous failures)
- We have never seen any signs of cesium deposits at the entrance to the RFQ
- We do not have any machine protection addressing the possibility of cesium in the beamline

## **FNAL**

#### Magnetron, continuous caesiation

D. Bollinger

Pictures from the last time the Einzel Lens Chopper was replaced (7/15/2015)

## Source facing side of Einzel Lens

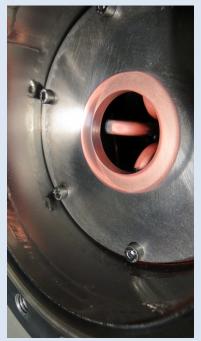


Blue tint has not been analyzed, likely not a cesium compound

#### Inside of Einzel Lens



Einzel Lens operates at 38kV, located U.S. of the RFQ. The lens has failed in the past due to insufficient design. Latest design has not failed in over 2 years. **RFQ** entrance

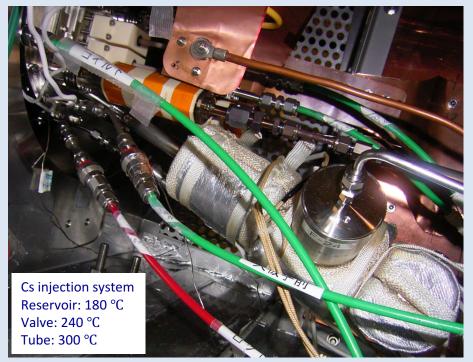


The only time we see the source facing side of the RFQ is when Einzel Lens is removed due to failure. It has been over 2 years since we had to change the lens

## **J-PARC**

#### RF source, very frequent caesiations

A. Ueno



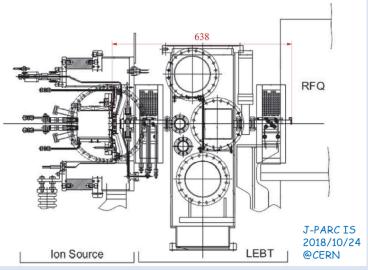


J-PARC IS Cs Injector without mantle heaters

J-PARC IS Cs Injector installed on Plasma Chamber with 3 mantle heaters for Reservoir, Valve (Fujikin FWBR-71-9.52#A) and Tube.

# Valve is remotely opened/closed by compressed air on/off.

The J-PARC 0.64m LEBT with a high space-charge limited current

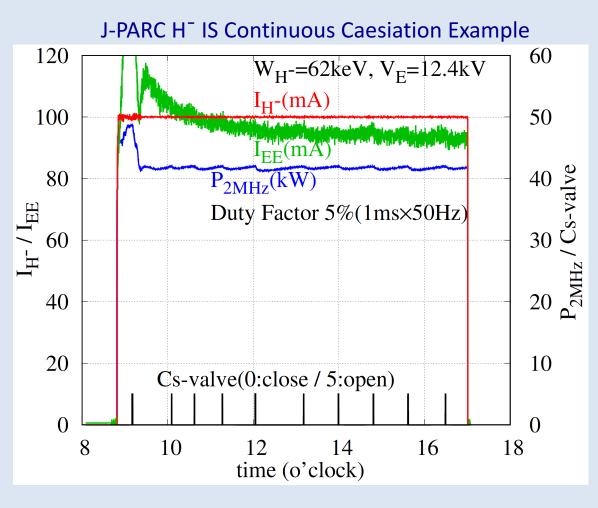


Source - RFQ distance is 64 cm

## **J-PARC**

#### RF source, very frequent caesiations

A. Ueno



For 5% duty (1 ms x 50 Hz) and 100 mA operation on **test-stand**, Cs density on plasma electrode was feedbacked by automatic opening Cs valve for about 40 s, which was estimated as 38.8  $\mu$ g per opening with 180 °C reservoir, to keep 2 MHz RF power lower than 42 kW.

For J-PARC operation steady state {1.75%(0.7 ms x 25Hz) RF-duty and 50 mA@LINAC exit ( $P_{2MHZRF}$ ~24 kW)}, typically Cs valve opens for about 45 s (43.7µg @T<sub>R</sub>=180 °C) each 70 minutes.

## J-PARC

## RF source, very frequent caesiations

Approximate Cs consumption per month or per year?

The estimated Cs consumption rate (with accuracy between 50%~200%) is
43.7 μg/70 minutes = 26.9 mg/month = 216 mg/year (8 months)

Do you also perform some Cs measurements or calibration tests?

Based upon very old experimentally measured time to empty 1 g Cs from 200 °C reservoir, it is calculated. The Cs consumption itself is not so important. The amount of the Cs leakage from the plasma electrode aperture determine the stability of the high voltage gaps and RFQ.

The total amount of Cs in your oven/system?

- **3g Cs** is installed **in the reservoir**, since some of it seems to combine with impurities inside Cs injector and air.

Measures and/or equipment to protect the linac - especially the RFQ - against Cs?

- Cs 852 nm spectrum is observed. If it exceeds the threshold value, then  $T_{Rset}=0$  °C (not used)
- No issue observed in the beam line and/or RFQ
- The amount of the Cs leakage was drastically decreased by decreasing the plasma electrode temperature from about 200 ℃ to 70 ℃

Observed / solved problems in the past, either associated with your Cs system or in the beamline.

- Cs valve maker: Swagelok -> Fujukin

13

A. Ueno

### Penning, continuous caesiation

#### D. Faircloth





Caesium ampoule being inserted into copper oven with thermocouple silver soldered to the bottom of oven When we are ready to run the copper oven and Cs ampoule are crushed with a tool

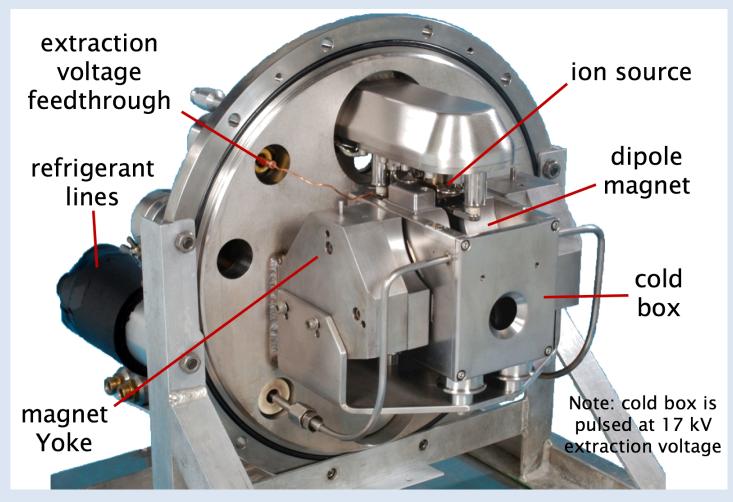
In normal operation the **Cs oven** is held **between 155 °C and 170 °C**. The Caesium temperature is slowly increased during the lifetime of the source (2-3 weeks) Cs consumption is **3 g/month**. The total amount of Cs in the oven/system is **5 g** 

Measures and/or equipment to protect the linac - especially the RFQ - against Cs? Beam comes out of the source then passes though a **90 degree dipole** in a **cold box** held at about **-5 °C** 

Penning, continuous caesiation

D. Faircloth

## Caesium Trapping: 'Cold Box'



# Penning, continuous caesiation

D. Faircloth

## Cold Box After Several Months' Use



- Maintain a positive nitrogen pressure in vessel during source changes
- Acetone wipe to remove excess Cs
- Ensure all cold box surfaces clean before installing new ion source
- Thorough cold box removal & maintenance every ~6 months



#### Penning source, continuous caesiation D. Faircloth

Observed / solved problems in the past, either associated with your Cs system or in the beamline.

- No problem with beamline in 35 years.
- First 20 years running directly into a 665 kV accelerating column.
- Second **15 years running into** a 3 solenoid LEBT and **RFQ**.

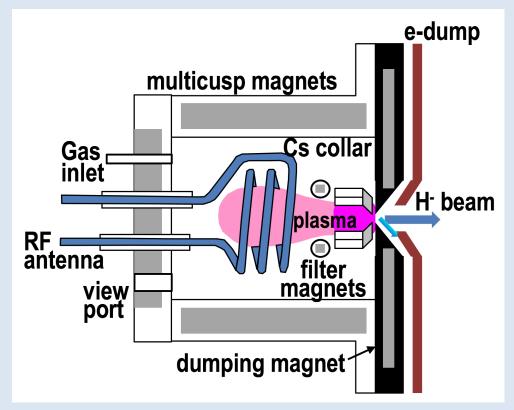
Various **problems** with Cs system **solved** over the years:

- Cs oven over-temperature prevented with inline thermal cut-out switches
- Cs purity increased to 99.99 %
- Tried pouring Cs directly into oven but reliability improvements not worth the increased handling precautions

## ORNL

RF source, heated Cs collar

#### The SNS Baseline Ion Source



**LBNL developed** and SNS improved the cesium-enhanced, RF-driven multicusp H<sup>-</sup> ion source, which delivers ~1-ms long H<sup>-</sup> current pulses at 60 Hz. M. Stockli

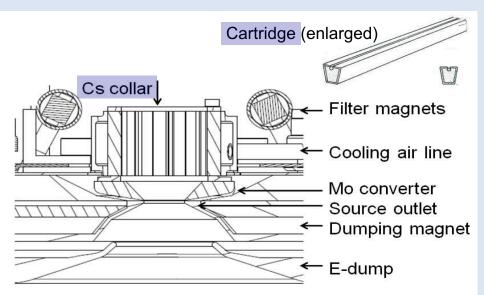
## ORNL

#### RF source, heated Cs collar

#### The Magic 30 mg Cs System:

•To minimize Cs-induced arcing in the SNS LEBT and nearby RFQ, LBNL implemented 8 Cs<sub>2</sub>CrO<sub>4</sub> cartridges from SAES Getters, which together contain <30 mg Cs. They are integrated into the Cs collar. The system compactness allows for rapid startups!

•The Mo ion converter is electrically and thermally attached to the Cs Collar. Heated air controls their temperature.



•Just after being evacuated, the Cs system is outgassed at 170°C and the Mo converter is sputter-cleaned with 6%, 50 kW, 2 MHz H plasma for 3 hours. Then the collar is heated for ~12 min. to 550°C to release ~4 mg of Cs\*. Then the temperature is lowered to ~180°C, with the converter remaining near 400°C, yielding a ~0.5 Cs layer. •Normally the H<sup>-</sup> beam grows for a few days by 1 or 2 mA.

•Then normally the H<sup>-</sup> beam becomes persistent, free of decay!

# **Over 7** A ·h of H<sup>-</sup> ions have been produced without any H<sup>-</sup> beam decay, maintenance or adding additional Cs!

M. Stockli

## ORNL

#### RF source, heated Cs collar

M. Stockli

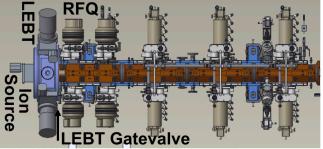
#### The Numbers\*, Protections, and Precautions

\*In the early days before our cesiations were optimized, 2-3 successful 30 minlong cesiations at 550°C could be executed with a single set of 8 cartridges. Apparently at 550°C the cartridges emit Cs for ~90 minutes. Having been able to reduce the cesiations to ~12 minutes, we appear to release only 4 mg in each cesiation.

Typically we use about 3-6 sources per year on the production frontend. Recessitions are very rare occurrences, mostly happing at the end of a run as a part of a ion source study.

This is a total yearly consumption of ~40 mg.

For the last year or so, there is a gate valve between the LEBT and the RFQ. This is closed, whenever we cesiate.



During cesiations in-line-of-sight surfaces get coated with Cs. This are issues with the 1<sup>st</sup> lens, which can draw excessive corona and the e-dump that can arc. However it appears that 3 hours of delay dissipates enough Cs to practically eliminate the e-dump arcing and overheating of the 1<sup>st</sup> lense of the 1<sup>st</sup> le

# Summary ion sources comparison (1/2)

Status August 2019	BNL	FNAL	RAL
H <sup>-</sup> source type	Magnetron	Magnetron	Penning
Caesiation method	continuous	continuous	continuous
Cs oven fill	5 g	5 g	5 g
Cs system temperatures	oven: 125-130 $^\circ\!\mathrm{C}$ (8h) then 90-110 $^\circ\!\mathrm{C}$ valve, tube: 300 $^\circ\!\mathrm{C}$	oven: 110 $^{\circ}$ C valve: 200 $^{\circ}$ C tube: 200 $^{\circ}$ C	oven: 155-170 $^\circ\!\mathrm{C}$ tube: 300 $^\circ\!\mathrm{C}$
Cs consumption	0.5 mg/h 4.38 g/year measured by left over	< 5 g/600 d < 3.0 g/year no measurements, 600 d based on experience, weighing oven foreseen	3 g/month 36 g/γear
Valve between Cs oven and ion source	manual valve Opened/closed only for source start/removal	manual valve Only time that they need to close that is when they let up the vacuum and remove the ion source	no valve Transport line as short as possible, could collect Cs and get blocked
Measures to protect the linac against Cs	none; LEBT with 45 degree bend	no method of trapping cesium coming out of the source	90 degree dipole, cold box
Observed issues with beamline, RFQ	never had any issues with Cs in RFQ	no issues with cesium in RFQ or HV element in LEBT	no problem with beamline in 35 years
Source-RFQ distance	2 m	1.2 m	1.5 m

All numbers and information kindly provided in July/August 2019 by D. Raparia (BNL), D. Bollinger (FNAL), D. Faircloth (RAL)

# Summary ion sources comparison (2/2)

Status August 2019	J-PARC	ORNL
H <sup>-</sup> source type	RF	RF
Caesiation method	not continuous, very frequent (with beam) 45 s each 70 min	not continuous, once per ~100 day long run
Cs oven fill	3 g	30 mg Cs in Cs collar as Cs <sub>2</sub> CrO <sub>4</sub>
Cs system temperatures	oven: 180 $^\circ  ext{C}$ valve: 240 $^\circ  ext{C}$ tube: 300 $^\circ  ext{C}$	Normally ~200 °C and raised to 550 $^\circ\!\mathrm{C}$ for ~12 min to activate St101 getter
Cs consumption	43.7 μg/70 min 0.328 g/year no measurements, estimated values	~40 mg/year including Cs for frontend R&D
Valve between Cs oven and ion source	pneumatic valve Opened/closed remotely by compressed air on/off	not applicable because Cs collar is an integral part of the ion source
Measures to protect the linac against Cs	Cs 852 nm spectrum observation	gate valve next to RFQ is closed during caesiations
Observed issues with beamline, RFQ	no issue in the beam line and/or RFQ observed	arcing problems resolved after introducing a 3-hour wait between caesiation and applying high voltages
Source-RFQ distance	0.64 m	0.1 m

All numbers and information kindly provided in July/August 2019 by A. Ueno (J-PARC), M. Stockli (ORNL)

## 2018 CERN Linac 4 ion source review – final report

Olli Tarvainen, Ursel Fantz, Dan Bollinger, Martin Stockli and Akira Ueno November 16<sup>th</sup>, 2018 Full report: EDMS 2048831 v.1

Continuous caesiation is seen important for the reliability of the 25 mA beam and the ultimate goal of 45 mA. These experiments directly support reaching the 25 mA goal. page 5

The work at the test stand after 2019 should concentrate on long-term experiments with the highest possible current using the RFQ box as a monitor. This allows the CERN team to master the caesium delivery process – in particular to determine whether occasional or continuous caesiation is the preferred choice for the high current operation. The committee is leaning towards continuous caesiation as it has better potential for maintaining the current over the foreseen 10 month run cycle. CERN should also investigate possibilities to determine the caesium consumption and leakage from the source under the high-current operation.

Caesiation should not be seen as a risk but as an opportunity.

Several labs run routinely in the caesiated mode and demonstrate reliable performances. page 4

## Summary

- For different ion source types (Magnetron, Penning, RF), presently in accelerator operation at BNL, FNAL, RAL, J-PARC, ORNL, five different Cs hardware installations and methods are summarized and compared in an upto-date review based on inputs (July/August 2019) from various lab experts.
- Continuous caesiations are done at BNL, FNAL, RAL, which are compared with the very frequent caesiations (without beam interruption) at J-PARC. A single shot caesition is performed at ORNL where the Cs source is an integral part of the ion source.
- Independent of the different methods applied, all other labs use caesiation temperatures  $T_{cs}$  (oven) > 100 °C.
- No lab reported any operational issues (beamline and/or RFQ) related to Cs.
- There is **little** to no **machine protection** applied (and needed) **at other labs**.
- Continuous caesiation was supported and recommended by external ion source review committee (Nov. 2018 report).